NSN 5961-01-019-8765

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Inclosure Material:

Metal

Overall Length:

Between 0.170 inches and 0.210 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

Internal Configuration:

Field effect-dual gate

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Features Provided:

Electrostatic sensitive and hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

-0.2 drain to source voltage and 18.0 drain to source voltage and 22.5 drain to gate voltage

Current Rating Per Characteristic:

50.00 milliamperes source cutoff current of standard range

Power Rating Per Characteristic:

330.0 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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